

A Comparison of Electronic Reliability Prediction Methodologies

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1. SUMMARY AND CONCLUSIONS

One of the most controversial techniques used at present in the field of reliability is the use of reliability prediction techniques based on component failure data for the estimation of system failure rates. The International Electronics Reliability Institute (IERI) at Loughborough University are in a unique position. Over a number of years a large amount of reliability information has been collected from leading British and Danish electronic manufacturing companies. This data is of such high quality that IERI are able to perform the comparison exercise with a number of boards of different types.

A number of boards were selected from the IERI field failure database and their reliability was predicted and compared with the actual observed performance in the field. The prediction techniques were based on the MIL-217E, HRD4, Siemens (SN29500), CNET, and Bellcore (TR-TSY-000332) models. For each method the associated published failure rates were used. Hence parts count analyses were performed on a number of boards from the database and these were compared with the failure rate observed in the field. The prediction values were seen to differ greatly from the observed field behaviour and from each other. Further analysis showed that each method of prediction was sensitive to widely different physical parameters.

This suggests that predictions obtained by the different models can't be compared and that great care should be taken when selecting a prediction technique since the physical parameters of the system will affect the prediction obtained in possibly unforeseen ways.

2. INTRODUCTION

Reliability prediction often effects major decisions in system design. It is based on the assumption that systems fail as a result of failures of component parts, and those parts fail partly as a result of exposure to application stress[1]. This means that by some consideration of the structure of such a piece of equipment and by further consideration of its usage it is possible to obtain an estimate of the systems reliability in that particular application.

There are many reasons why this task may be necessary. These include feasibility evaluation where the compatibility of a design concept is weighed against the design reliability requirements for acceptance, and design comparison where different parts of a system can be compared and any necessary trade off such as cost, reliability, weight etc. can be made. Further uses are for the identification of potential reliability problems and as a reliability input into other tasks such as maintainability analysis, testability evaluations and FMECA. [2]

Electronic failure prediction methodology (EFPM) is normally carried out in two stages. The first stage is known as parts count analysis and requires comparatively little information about the system. This method is generally used early in the design phase to obtain a preliminary estimate of the system reliability. The second stage is known as parts stress analysis and involves detailed knowledge about the system but can, in principle, provide a more realistic estimate of the reliability. The parts stress method tends to be used towards the end of the design cycle when actual circuit parameters have been established.

Rightly or wrongly reliability prediction methods are widely accepted throughout the electronics industry. These methods are often used as a yardstick for the comparison of different equipment. However, many manufacturers have commented that the models can be wildly inaccurate when compared with the performance in the field, particularly in the case of the observed failure rates of modern microelectronic devices, and their use can lead to increased costs and complexity while deluding engineers into following a flawed set of perceptions and leaving truly effective reliability improvement measures unrecognised[1].

In general the telecommunication industry models offer improved accuracy when compared to other models due primarily to the quantity and quality of in house data on mature equipment but tend to be less accurate for newer designs and for similar systems produced by other industries. The main advantage of the MIL-217 approach is its wide acceptance throughout the defence industry. This enables it to be used as a general yardstick which allows comparison between different equipment. However it has many shortcomings which have been the subject of much discussion on recent years.

IERI at Loughborough University are in an unique position. A collaborative exercise involving a number of British and Danish electronic systems manufacturers has resulted in the establishment of a database containing high quality data at the system, board and component level. This has enabled IERI to carry out predictions on a large number of boards and to compare these with observed performance in the field. The initial investigation involved parts count analysis only and It should be stated that some of the predictions described in this paper were performed using older versions of some of the handbooks that have more recently been updated. This means that although the principles of the prediction remain the same the actual figures obtained from these now obsolete handbooks may differ from those obtained from the new, updated versions.

3. THE THEORY OF RELIABILITY PREDICTION

A electronic system can be considered to be a network of components all interconnected to one another in various complex ways. This real life model is however unsuitable for reliability analysis since it is far too complex. In order to study the reliability of systems a number of assumptions need to be made.

1) Any component failure causes a system failure.

This is normally modelled as a series configuration (or chain structure). This is the simplest of the many models available and as such is the most widely used for reliability modelling of systems. A series configuration of n items will have a reliability function defined by (1)

$$R(t) = P(x_1, x_2, \dots, X_n) = P(x_1)P(x_2|x_1)P(x_3|x_1x_2) \dots P(x_n|x_1x_2\dots x_{n-1}) \quad (1)$$

where $P(x_1)$ etc. Is the probability that item X_1 will fail and $P(x_2|x_1)$ etc. is the conditional probability that X_2 will fail given X_1 has failed.

2) *The components that make up the system must be independent, This means that a failure by a single component must not affect other components in the system.*

If the n items x_1, x_2, \dots, x_n are independent, then

$$R(t) = P(x_1)P(x_2)\dots P(x_n) = \prod_{i=1}^n p(x_i) \quad (2)$$

This suggests that assuming that no component failure affects any other then the reliability of a system made up of these components can simply be calculated by multiplying the probability of failure for each component in the system together. However in a general system this can be difficult since each component's probability of failure could be a complex function. If however simple functions are used then it is possible to proceed further.

3) *The component failure behaviour must be governed by a constant-hazard model*

This last assumptions means that if the component model is $e^{-\lambda_i t}$ then equation (2) becomes

$$R(t) = \prod_{i=1}^n e^{-\lambda_i t} = e^{(-\sum_{i=1}^n \lambda_i t)} \quad (3)$$

This equation is the not only the most commonly used and the most elementary system reliability formula it is also the most commonly abused. It should be remembered that in order for this equation to be valid then the condition given in clause 3 above must be met. There is ample evidence to suggest that this is not in fact the case [4] but data handbook suppliers and users still assume that this is true. Recently methodologies have been developed [5] that will allow prediction of system reliability but do not make this assumption.

4. OVERVIEW OF PREDICTION METHODOLOGIES

In most of the available prediction methodology handbooks the equation for the reliability of a system given in equation (3) is modified by the addition of different multipliers, called Ξ factors. These Ξ factors relate to parameters which can effect the overall reliability of a system such as environment, stress level, temperature etc. In general the equation for system failure rate , given the failure rate of the constituent components, will be

$$\lambda_{SS} = \Pi_E \sum_{i=1}^n \lambda_{G_i} \cdot \sum_{k=1}^m \pi_{F_k} \cdot N_i \quad (4)$$

where λ_{G_i} is generic failure rate for the i 'th device, Π_{F_k} is the stress factor multiplier for the k 'th stress type for the i 'th device, N_i is the quantity of i 'th device type, and Π_E is the environment factor for the system.

Each model used in this paper uses an equation similar to (4) and is described briefly below.

4.1 BELLCORE

This method is defined in [6] and was developed by Bell communications research for use by the electronics industry so that they would be aware of Bellcore's view of the requirements of reliability prediction procedures for electronic equipment's. The data presented is based upon field data, laboratory tests, MIL-HDBK-217E, device manufacturers data, unit suppliers data or engineering analysis. The Ξ factors used in this model take into account the variations in equipment operating environment, quality and device application conditions such as device temperature and electrical stress level.

4.2 CNET

This method is defined in [7] and was developed by French National Centre Of Telecommunications. The data used comes from the analysis of breakdowns of the equipment used by the military and civil Administration, and other equipment and component manufacturers. This handbook forms a common base intended to make reliability predictions uniform in France. The Ξ factors used in this model take into account the variations in equipment operating environment, quality and device temperature. It should be noted that the method used in this paper is the 'simplified method' so called because it comes from a British Telecom translation of the important parts of the actual CNET handbook.

4.3 HRD4

This method is defined in [8] and was developed by British Telecom Materials and Components Centre for use by designers and users of electronic equipment so that there exists a common basis exists for system reliability prediction. The generic failure rates given in the handbook are estimates of the upper 60% confidence levels, based upon, wherever possible, data collected from the in service performance of the equipment installed in the UK inland telecommunications network. Where such data is not available for particular components, alternative sources or estimated values have been used and the status of the source indicated by a letter code. The Ξ factors used in this model take into account the variations in equipment operating environment, quality and device temperature.

4.4 MIL-217

Mil-Hdbk-217[9] was developed by the US Department of Defence with the assistance of the military departments, federal agencies, and industry for use by the electronic manufacturers supplying to the military. The handbook describes two methods, namely parts count and parts stress which are used to predict the reliability of electronic components, systems, or subsystems in different stages of the design. The failure rates given in the handbook have in

the main derived from test bed and accelerated life studies. The Ξ factors used in this model take into account the variations in equipment operating environment, and device quality.

4.5 SIEMENS

This method is defined in [10] and was developed by Siemens AG for the use of Siemens and Siemens associates as a uniform basis for reliability prediction. The standard presented in the document is based on failure rates under specified conditions. The failure rates given were determined from application and testing experience taking external sources (e.g. Mil-Hdbk-217) into consideration. Components are categorised into many different groups each of which has a slightly different reliability model. The Ξ factors used in this model take into account the variations in device operating temperature and electrical stress.

5. ANALYSIS OF PREDICTION METHODOLOGIES

Six different board designs were selected from the IERI database. These designs were chosen such that they contained a wide range of component types and were from several different applications. Table 1 describes the environments and applications of the boards.

Table 1: Brief description of the circuit boards

| BOARD | ENVIRONMENT | APPLICATION |
|-------|---------------|--------------------|
| 1 | Ground Mobile | Radio System |
| 2 | Ground Mobile | Radio System |
| 3 | Ground Benign | Telephone Exchange |
| 4 | Ground Benign | Telephone Exchange |
| 5 | Ground Mobile | Command System |
| 6 | Ground Mobile | Command System |

The analysis of two of the boards will be given in detail to show the methodology and to illustrate how the models can be used for parts provisioning purposes.

5.1 CIRCUIT BOARD ONE

The first board design chosen from the IERI database contained 338 components with six different component types. The board came from a system used in a high quality radio application. Table 2 contains the predicted failure rate for each component type used on the board. Each failure rate is given in FITs and is the failure contribution for each component type on the board taking into consideration environment, component numbers etc.

Table 2: Contribution to failure rate by each component type for circuit board one.

| DEVICE | BELLCORE | CNET | HRD4 | MIL-217 | SIEMENS |
|---------------------------------|--------------|--------------|-------------|-------------|-------------|
| Ceramic Multilayer Capacitor | 210 | 45 | 3 | 4 | 35 |
| pn-Junction Diode | 125 | 300 | 300 | 9 | 25 |
| Bipolar Digital IC | 936 | 390 | 168 | 50 | 60 |
| Metal Oxide Resistor | 1590 | 596 | 51 | 52 | 795 |
| Discrete Bipolar Transistor | 7812 | 20937 | 4000 | 1225 | 1250 |
| Tantalum Electrolytic Capacitor | 1350 | 3780 | 40 | 594 | 180 |
| Total | 12023 | 26048 | 4562 | 1934 | 2345 |

As can be seen from the totals row in Table 2 the reliability predicted for this board differs widely between the different models. The actual field behaviour of this board is summarised in Table 3 which shows the actual numbers of operating hours observed, the total number of failure in this time and the calculated failure rate with the upper and lower 95% σ^2 confidence limits.

Table 3: Actual field behaviour for circuit board one.

| | |
|---------------------------------------|---------|
| Number of failures | 19 |
| Total number of operating hours | 4444696 |
| FIT rate | 4274 |
| Upper 95% σ^2 confidence limit | 6400 |
| Lower 95% σ^2 confidence limit | 2572 |

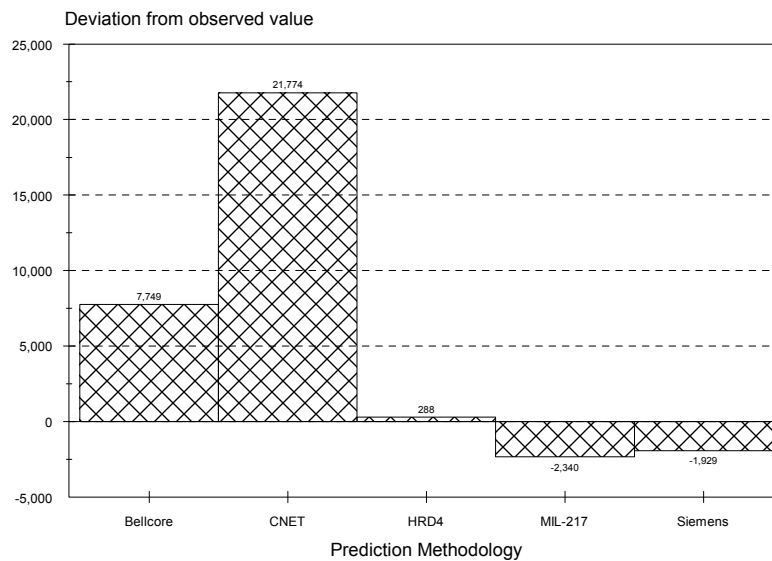


Figure 1: Deviation of predicted reliability of board one from observed value using different models

The differences from the various predicted values to the actual field figures are summarised in Figure 1. It can be seen that some of the models gave predictions that were optimistic (MIL-217 and Siemens) whereas others give pessimistic predictions. Table 4 shows the percentage contribution to failure of each component on the circuit board. It is found that for each prediction model that the most likely cause of failure was the bipolar transistor which has the largest percentage contribution to failure in each case.

Table 4: Largest percentage contributions to failure for circuit board one.

| PREDICTION MODEL | LARGEST CONTRIBUTION | NEXT LARGEST CONTRIBUTION |
|------------------|--------------------------|---------------------------------------|
| Bellcore | Bipolar Transistor (65%) | Metal Oxide Resistor (13%) |
| CNET | Bipolar Transistor (80%) | Tantalum Electrolytic Capacitor (14%) |
| HRD4 | Bipolar Transistor (87%) | pn-Junction Diode (6.5%) |
| MIL-217 | Bipolar Transistor (63%) | Tantalum Electrolytic Capacitor (30%) |
| Siemens | Bipolar Transistor (53%) | Metal Oxide Resistor (33%) |

Analysis of the field information shows that the bipolar transistor was the main cause of failure of this circuit board in the field, and so spare provisioning using any of the available models would have proved accurate.

5.2 CIRCUIT BOARD TWO

The second board chosen from the IERI database was slightly more complex board containing 149 components with eighteen different component types. The board comes from a system used in a telecommunication application. Table 5 contains the predicted failure rate in FITs for each component type used on the board.

Table 5: Contribution to failure rate by each component type for circuit board two.

| DEVICE | BELLCORE | CNET | HRD4 | MIL-217 | SIEMENS |
|--|-------------|-------------|---------------|---------------|-------------|
| Transformer | 3 | 9 | 7 | 6 | 5 |
| Coil activated relay | 770 | 605 | 440 | 1430 | 88 |
| Aluminium electrolytic capacitor | 210 | 22 | 120 | 16 | 120 |
| Polyester capacitor | 17 | 4 | 6 | 1 | 14 |
| pn-Junction diode | 230 | 149 | 345 | 152 | 230 |
| Zener diode | 16 | 63 | 87 | 94 | 350 |
| LED | 9 | 15 | 280 | 65 | 0 |
| Bipolar digital IC (11-100 gates) | 59 | 413 | 7 | 3 | 20 |
| Bipolar linear IC (1-10 transistors) | 14 | 57 | 13 | 3 | 500 |
| Bipolar linear IC (11-100 transistors) | 42 | 80 | 13 | 3 | 150 |
| MOS digital IC (1-10 gates) | 83 | 903 | 27 | 3 | 40 |
| Rectangular connector | 7 | 1 | 50 | 8 | 22 |
| Varistor | 6 | 0 | 10 | 0 | 10 |
| Carbon film resistor | 182 | 27 | 10 | 11 | 26 |
| Wire-wound resistor | 127 | 42 | 6 | 1 | 30 |
| Metal film resistor | 7 | 25 | 0.5 | 0.5 | 2 |
| Rocker switch | 5 | 44 | 30 | 1 | 20 |
| Bipolar transistor | 25 | 19 | 16 | 38 | 20 |
| TOTAL | 1812 | 2478 | 1467.5 | 1835.5 | 1647 |

As can be seen from the totals row the reliability predicted for this board also differs widely between the different methods. The actual field behaviour of this board is summarised in Table 6 and the difference between the predicted values and the observed field value is shown in Figure 2

Table 6: Actual field behaviour for circuit board two.

| | |
|-------------------------------------|-------------------|
| Number of failures | 5 |
| Total number of operating hours | 8.5×10^6 |
| FIT rate | 587 |
| Upper 95% χ^2 confidence limit | 1202 |
| Lower 95% χ^2 confidence limit | 190.6 |

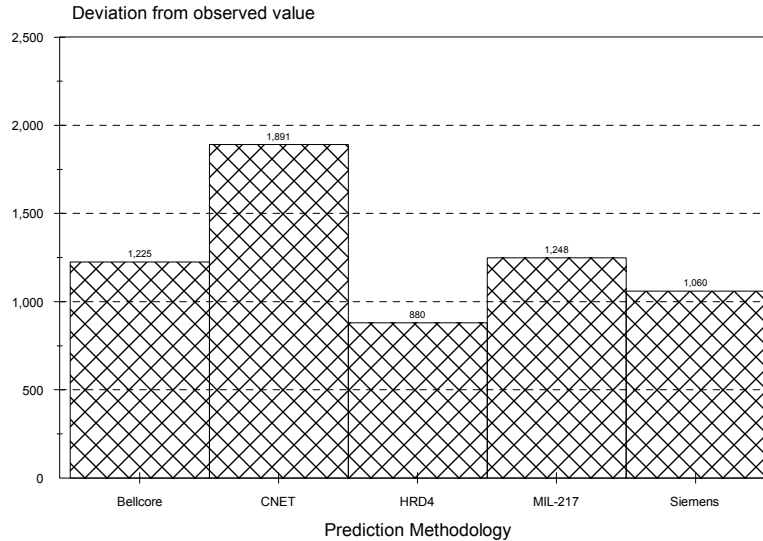


Figure 2: Deviation of predicted reliability from observed values for different models

Notice in this case all predictions are pessimistic. The percentage contribution to failure of each component on the circuit board is shown in Table 7.

Table 7: Largest percentage contributions to failure for circuit board two.

| PREDICTION MODEL | LARGEST CONTRIBUTION | NEXT LARGEST CONTRIBUTION |
|------------------|---|----------------------------|
| Bellcore | Coil Activated Relay (42%) | pn-Junction Diode (12%) |
| CNET | MOS Digital IC with 1-10 gates (36%) | Coil Activated Relay (24%) |
| HRD4 | Coil Activated Relay (30%) | pn-Junction Diode (23%) |
| MIL-217 | Coil Activated Relay (77%) | pn-Junction Diode (8%) |
| SIEMENS | Bipolar Linear IC with 1-10 transistors (30%) | Zener Diode (21%) |

Field observation showed all the failures on this board to be caused by coil activated relays and bipolar transistors with the relay causing one more failure than the transistor. If parts provisioning had been done according to two of the models, then the incorrect part would have been identified.

The reliability of the rest of the boards used in this study were calculated using all the aforementioned models. Figure 3 shows the percentage deviation from the observed field failure rate for the six board designs selected from the IERI-CORD database. The predictions not only differ widely between the various models but they also differ greatly from the observed field failure rate. The models are not always consistent in the deviation from this observed field value, they can be optimistic in some cases while pessimistic in others. This suggests that there are some underlying factors that are causing divergence of the models.

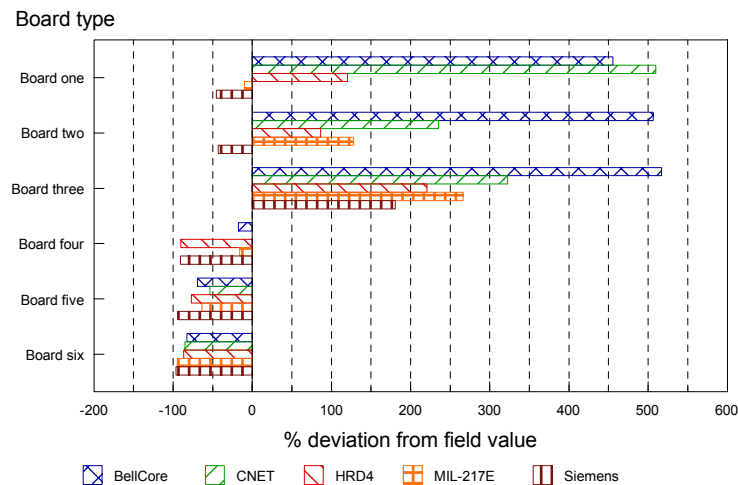


Figure 3: Percentage deviation from the observed field value for six boards

In order to investigate this apparent inconsistency in the various models it is necessary to look at each model carefully and analyse the way in which the predicted failure rate is influenced by the various parameters that influence system performance. This technique is known as sensitivity analysis and it is useful when examining a model for major dependencies.

If the various prediction models are sensitive to similar parameters then the inconsistency shown above must come from the nature of the underlying data. If the models are sensitive to different parameters then this suggests that different models of failure were used when the models were derived. Hence this makes it impossible to use base failure rates from one model in another and also makes it imperative to only use in house data derived in the same manner as the chosen model when extending the coverage of the model to such things as custom components. This makes it much more difficult for companies performing predictions to use data gathered in house.

6. SENSITIVITY ANALYSIS OF PREDICTION METHODOLOGIES

This is done by varying temperature, quality, stress, and environment in turn while keeping the others at typical or nominal values. The results are presented graphically and show percentage variation of predicted failure rate from the nominal value while a single parameter is varied within the limits that the models allow. The largest spread shows the parameter that has the greatest effect on the model's prediction. Care should be taken in some cases where the effect is accentuated by a highly non-linear variation in one of the parameters' Ξ factors. This is particularly true when the parameters are discrete, as in the case of environment, where selection of a particular environment can cause a large change in the associated Ξ factor. The degree of non-linearity can be demonstrated using graphs of normalised stress versus deviation where normalised stress is defined as the ratio between values of the range of available Ξ factors and the nominal Ξ factor value for the parameter under investigation.

6.1 BELLCORE MODEL

The percentage deviation in the board failure rate from the nominal with respect to different stress levels using the Bellcore methodology is shown in Figure 4.

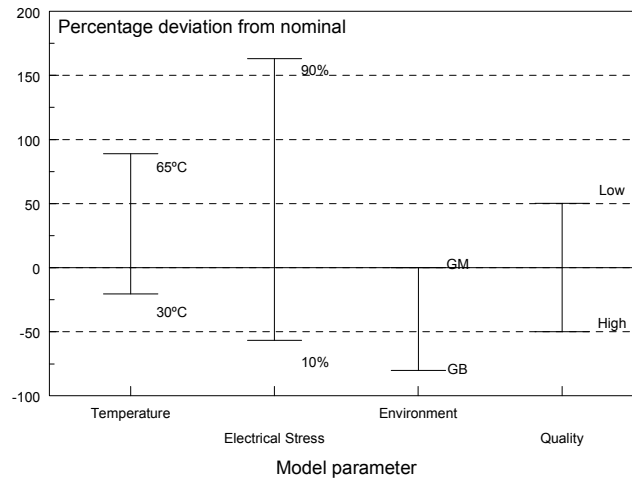


Figure 4: Sensitivity of predicted value for the Bellcore methodology

As can be seen Figure 4 the allowed variation in the electrical stress makes the largest difference to the calculated failure rate.

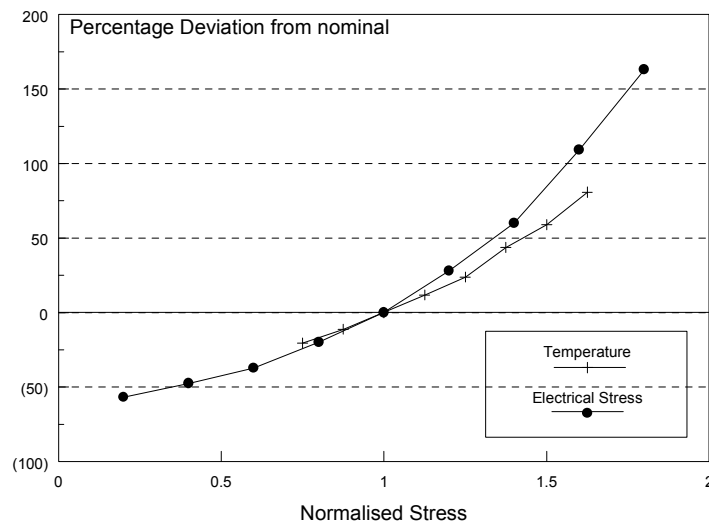


Figure 5: Variation in predicted value for the Bellcore methodology with changes in temperature and electrical stress.

The non-linear nature of the effect of varying electrical stress and temperature are shown in Figure 5. This shows that the BELLCORE model is based upon an Arrhenius style acceleration formula which is reflected in this non-linearity.

6.2 CNET MODEL

Figure 6 shows the percentage deviation in the board failure rates with respect to different stress levels using the CNET(simplified) methodology. As can be seen from Figure 6, the range in quality factor has the largest influence on the calculated failure rates.

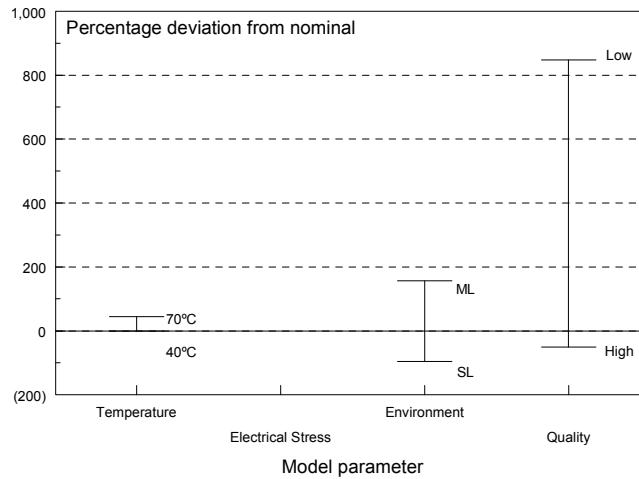


Figure 6: Sensitivity of predicted value for the CNET methodology

The quality factor used in this model is based upon a set of discrete quality bands over which the Ξ factor is defined. This means that the quality factor is a stepwise non-linear function of the device quality.

6.3 HRD4 MODEL

The percentage deviation in the board failure rates with respect to different stress levels using the HRD4 methodology is shown in Figure 7.

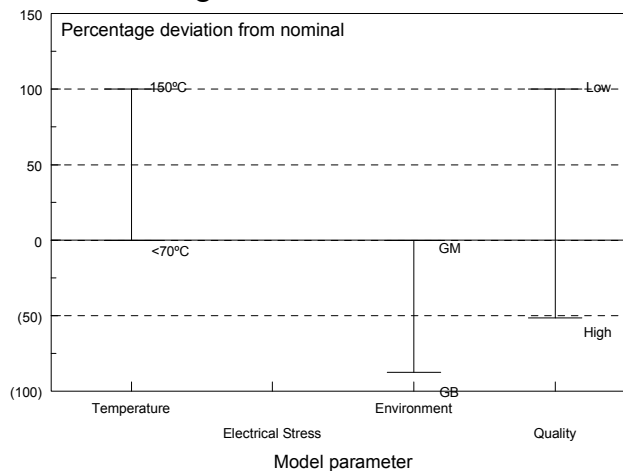


Figure 7: Sensitivity of predicted value for the HRD4 methodology

As can be seen from Figure 7, it is the allowed range of quality factors that makes the largest difference to the calculated failure rates. The quality factor used in this model is based upon a set of discrete quality bands over which the Ξ factor is defined. Again this means that the quality factor is a stepwise non-linear function of the device quality.

6.4 MIL-217 MODEL

Figure 8 shows the percentage deviation in the board failure rates with respect to different stress levels using the MIL-217E methodology. The figure shows that it is the allowed

variation in environment factors that causes the largest difference in the calculated failure rates.

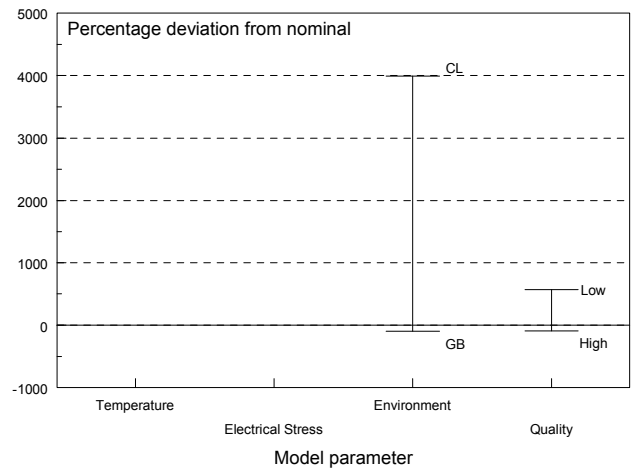


Figure 8: Sensitivity of predicted value for the MIL-217 methodology

However this effect is enhanced because of the large difference caused by the cannon launch (CL) environment as is apparent from Figure 9.. If the CL environment is omitted then the quality would become the predominant factor.

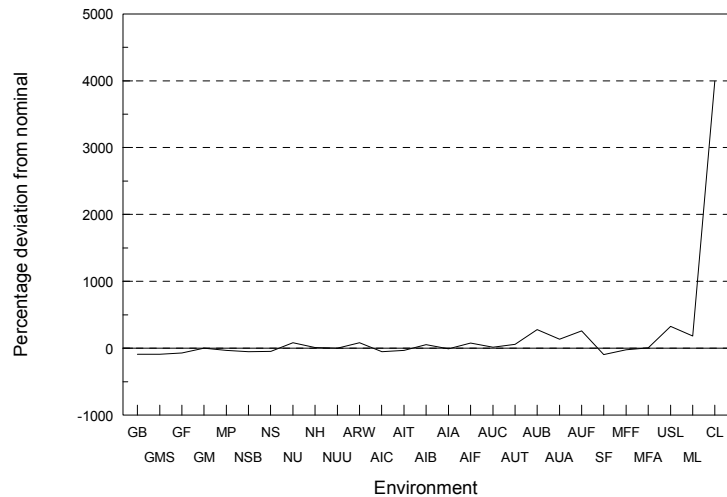


Figure 9: The effect of MIL-217 Environments on the predicted value

The quality factor used in this model is based upon a set of discrete quality bands over which the Ξ factor is defined. This means that the quality factor is a stepwise non-linear function of the device quality.

6.5 SIEMENS MODEL

The percentage deviation in the board failure rates with respect to different stress levels using the Siemens methodology is shown in Figure 10. As can be seen from the figure it is the range of temperature factor that causes the largest difference in the calculated failure rates.

The non-linear nature of the electrical stress and temperature effects are shown in Figure 11
 This

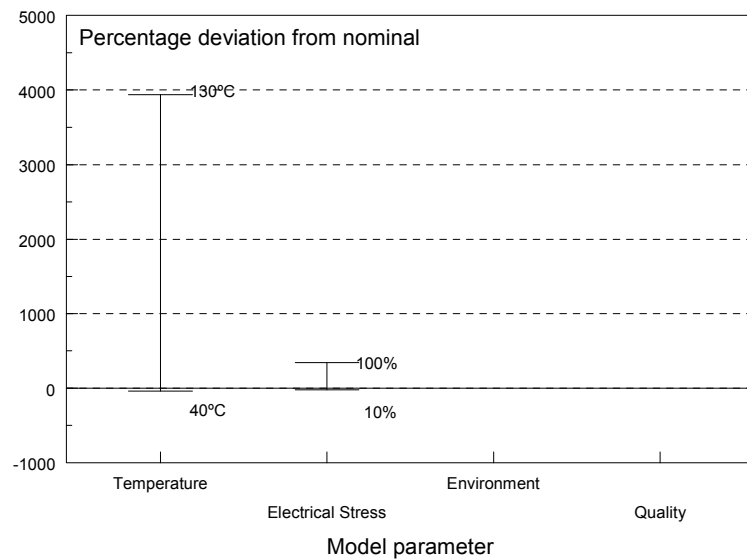


Figure 10: Sensitivity of predicted value for the Siemens methodology

means that the Siemens model is based upon an Arrhenius style acceleration formula which is reflected by this non-linearity.

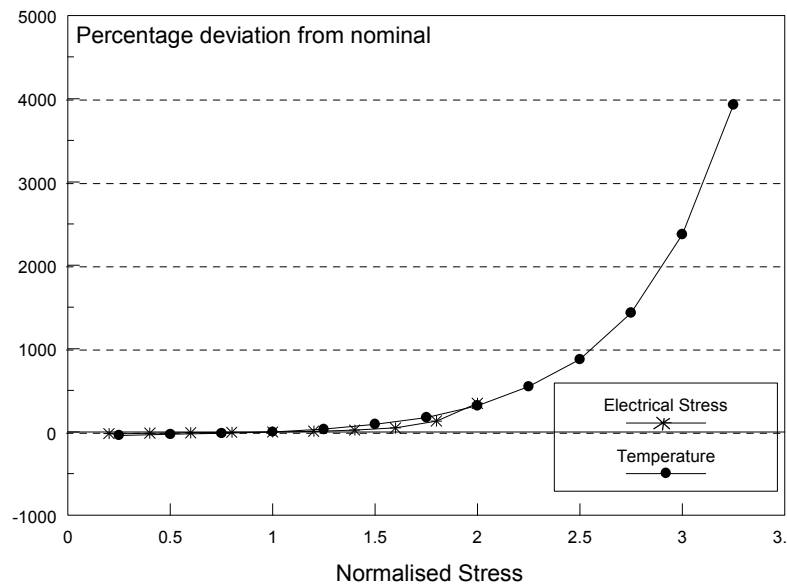


Figure 11: Variation in predicted value for the Siemens methodology as temperature and electrical stress are varied.

7. CONCLUSIONS

The results are summarised in Table 7. It is evident that some of the models are more sensitive to a Ξ factor that varies according to an Arrhenius model, such as temperature and electrical

stress, while others are more sensitive to the discrete Ξ factors used to model environment and quality.

Table 7: Most sensitive parameter in each prediction model

| Prediction Model | Greatest sensitivity |
|------------------|----------------------|
| Bellcore | Electrical Stress |
| CNET(Simplified) | Quality |
| HRD4 | Quality |
| MIL-217E | Environment, Quality |
| Siemens | Temperature |

It is not surprising that direct comparisons of the models result in wide variations. Although the models are based upon the same criteria there is disagreement about the effects the different parameters have on the failure rate.

Also by carefully examining the models, it was observed that although the quality levels are clearly defined within each procedure, it is extremely difficult to find a quality level description that is compatible across all models. In addition every organisation has developed their model according to the experience they have obtained in the field and have tailored the model to meet their specific needs.

It is inadvisable to compare the models' prediction with field performance unless the systems used are manufactured according to the guidelines and procedures that are specified by the model designers. Under such circumstances the system manufacturers would argue that their models are suitable for reliability prediction.

Care must also be taken when comparing the predicted reliability with that observed in the field as prediction models assume a constant hazard rate. It has been observed however that early life failures do occur in the field even after system burn-in [4]

Even if the above considerations are taken into account, there is no guarantee that the field reliability will be the same as that predicted. This is due to the underlying reason that models are generally simple empirical approximations. Indeed it is postulated that because of this, their use should actively be discouraged. Moreover, they do not take into account many of the other critical factors such as vibrations, mechanical shock, etc.

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